

View Online at <https://aerobasegroup.com/nsn/5961-00-402-1558>

Inclosure Material:

Metal

Overall Length:

0.185 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.370 inches

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

60.0 collector to emitter voltage/static/base open all transistor and 80.0 collector to emitter voltage, dc all transistor and 100.0 collector to base voltage, dc all transistor and 7.0 emitter to base voltage, dc all transistor

Current Rating Per Characteristic:

500.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

3.0 watts small-signal input power, common-collector absolute all transistor

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Internal junction configuration transistor npn

Test Data Document:

96214-531026 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

6 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

A110a0